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<b>INFORMATION DISCLOSURE STATEMENT BY APPLICANT</b> (use as many sheets as necessary)				Application Number	10/621,188
				Filing Date	July 15, 2003
				First Named Inventor	Chlan-Wei Li
				Art Unit	1765
				Examiner Name	Karl E. Group
Sheet	1	of	1	Attorney Docket Number	H0005039-3002

U.S. PATENT DOCUMENTS					
Examiner Initials*	Cite No. <sup>1</sup>	Document Number	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear
		Number - Kind Code <sup>2</sup> (if known)			
h		US-4,234,343	11/18/1980	Andersson	
h		US-4,401,768	08/20/1983	Morgan	
h		US-5,219,600	08/15/1993	Yoshida et al.	
h		US-5,523,267	08/04/1996	Tanaka et al.	
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		US-			
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FOREIGN PATENT DOCUMENTS					
Examiner Initials*	Cite No. <sup>1</sup>	Foreign Patent Document	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear
		Country Code <sup>2</sup> - Number <sup>3</sup> - Kind Code <sup>4</sup> (if known)			
h		PCT International Search Report PCT/US2004/022884	12/08/2004		
h		PCT Written Opinion	12/08/2004		
h		JP 2000 247748 A	08/12/2000		

NON PATENT LITERATURE DOCUMENTS				
Examiner Initials*	Cite No. <sup>1</sup>	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.		T <sup>2</sup>
h		GIUSEPPE PEZZOTTI and HANS-JOACHIM KLEBER, Effect of Residual Microstresses at Crystalline Multigrain Junctions on the Toughness of Silicon Nitride, Journal of the European Ceramic Society, Elsevier Science Publishers, Barking, Essex, GB, vol. 19, no. 4, April 1999, pp. 491-495.		
h		HEON-JIN CHOI, JUNE-GUNN LEE and YOUNG-WOOK KIM, High Temperature Strength and Oxidation Behaviour of Hot-Pressed Silicon Nitride-Silicate Ceramics, Journal of Materials Science, Chapman and Hall Ltd., London, GB, vol. 32, no. 7, April 1997, pp. 1937-1942.		
Examiner Signature	Karl E. Group		Date Considered	4/6/05

\*Examiner: Initial if reference considered, whether or no citation is in conformance with MPEP 608. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

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